

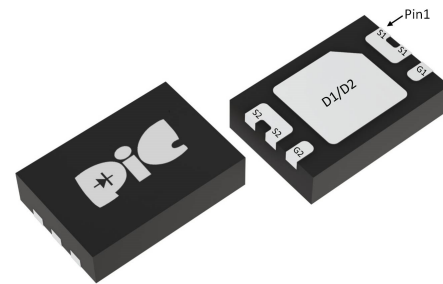
➤ General Description

The PAN82TE04F the low R_{DS(on)} trench N-CH MOSFETs with robust ESD protection. This product is suitable for Lithium-ion battery pack applications. The efficiency for power switching and load switching application., this device also comply with the RoHS and Green Product requirement with full function reliability approved.

➤ Feature

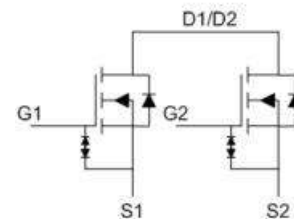
- Low drain-source ON resistance
- Green Device Available
- ESD Protected Embedded
- DFN2X3-6L package design

➤ DFN2X3-6L



➤ Application

- Load Switch
- Portable Equipment
- Battery Powered System



➤ Absolute Maximum Ratings

Parameter	Symbol	Rating	Units
Drain-Source Voltage	V_{DS}	20	V
Gate-Source Voltage	V_{GS}	± 12	V
Continuous Drain Current, V_{GS} @ 4.5V ₁	$I_D@T_A=25^\circ C$	9.5	A
Continuous Drain Current, V_{GS} @ 4.5V ₁	$I_D@T_A=70^\circ C$	7.6	A
Pulsed Drain Current ₂	I_{DM}	60	A
Total Power Dissipation ₁	$P_D@T_A=25^\circ C$	1.56	W
Storage Temperature Range	T_{STG}	-55 to 150	$^\circ C$
Operating Junction Temperature Range	T_J	-55 to 150	$^\circ C$
Thermal Resistance Junction-Ambient ₁ ($t \leq 10s$)	$R_{\theta JA}$	80	$^\circ C/W$

➤ Electrical Characteristics ($T_J=25^\circ C$ Unless otherwise noted)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{GS}=0V, I_D=250\mu A$	20	---	---	V
Static Drain-Source On-Resistance ²	$R_{DS(ON)}$	$V_{GS}=4.5V, I_D=5A$	6.3	7.8	9	m Ω
		$V_{GS}=4.0V, I_D=5A$	6.5	8.0	9.5	
		$V_{GS}=3.7V, I_D=5A$	6.7	8.2	10	
		$V_{GS}=3.1V, I_D=5A$	7.0	9.0	11.2	
		$V_{GS}=2.5V, I_D=5A$	8.0	10.5	13.5	
Gate Threshold Voltage	$V_{GS(th)}$	$V_{GS}=V_{DS}, I_D=250\mu A$	0.5	---	1.2	V
Drain-Source Leakage Current	I_{DSS}	$V_{DS}=16V, V_{GS}=0V, T_J=25^\circ C$	---	---	1	μA
		$V_{DS}=16V, V_{GS}=0V, T_J=55^\circ C$	---	---	5	
Gate-Source Leakage Current	I_{GSS}	$V_{GS}=\pm 8V, V_{DS}=0V$	---	---	± 10	μA
Forward Transconductance	g_{fs}	$V_{DS}=5V, I_D=5.5A$	---	38	---	S
Total Gate Charge (4.5V)	Q_g	$V_{DS}=15V, V_{GS}=4.5V, I_D=5.5A$	---	22	---	nC
Gate-Source Charge	Q_{gs}		---	3.1	---	
Gate-Drain Charge	Q_{gd}		---	8.2	---	
Turn-On Delay Time	$T_{d(on)}$	$V_{DD}=15V, V_{GS}=4.5V, R_G=6\Omega, I_D=5.5A$	---	10	---	ns
Rise Time	T_r		---	39.5	---	
Turn-Off Delay Time	$T_{d(off)}$		---	65	---	
Fall Time	T_f		---	30	---	
Input Capacitance	C_{iss}	$V_{DS}=10V, V_{GS}=0V, f=1MHz$	---	1647	---	pF
Output Capacitance	C_{oss}		---	170	---	
Reverse Transfer Capacitance	C_{rss}		---	148	---	

➤ Diode Characteristics

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Continuous Source Current ¹	I_S	$V_G=V_D=0V, \text{Force Current}$	---	---	9.5	A
Pulsed Source Current ²	I_{SM}		---	---	60	A
Diode Forward Voltage ²	V_{SD}	$V_{GS}=0V, I_S=9.5A, T_J=25^\circ C$	---	---	1.2	V

Note :

1.The data tested by surface mounted on a 1 inch² FR-4 board with 2OZ copper, $t \leq 10s$.

2.The data tested by pulsed , pulse width $\leq 10\mu s$, duty cycle $\leq 1\%$

➤ Typical Characteristics

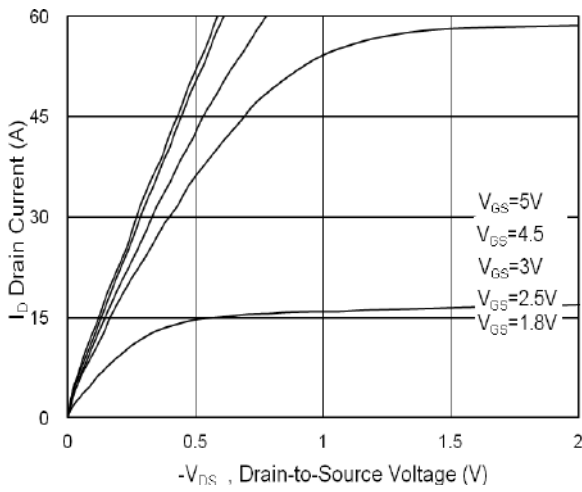


Fig.1 Typical Output Characteristics

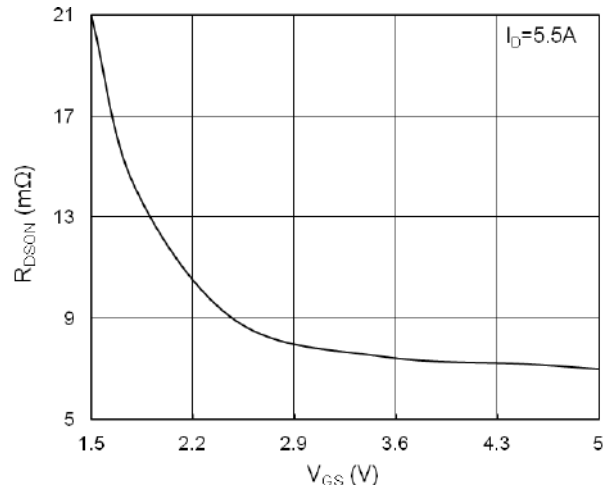


Fig.2 On-Resistance vs. G-S Voltage

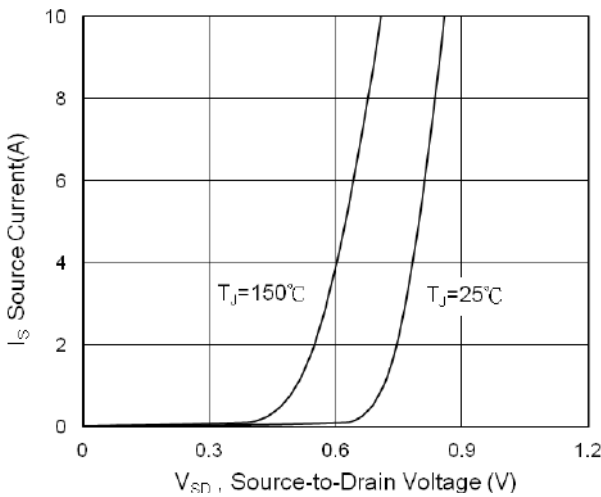


Fig.3 Forward Characteristics of Reverse

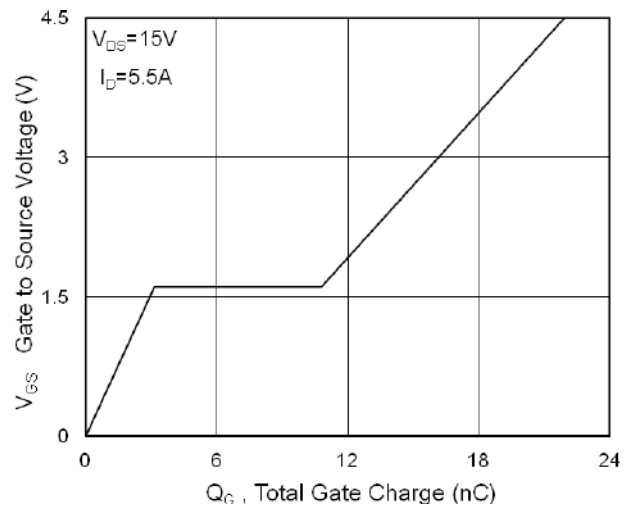


Fig.4 Gate-Charge Characteristics

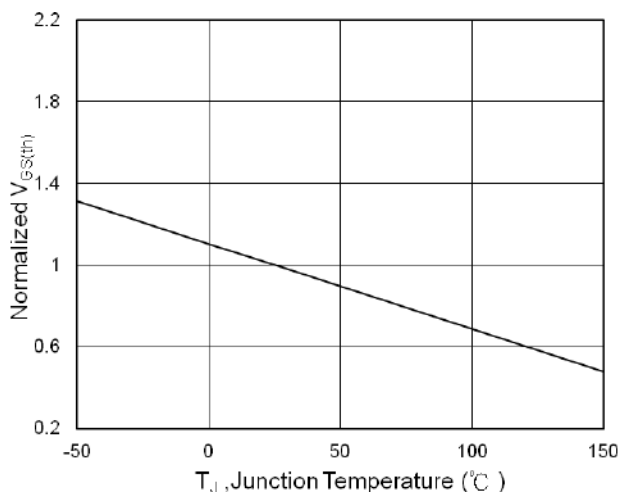


Fig.5 $V_{GS(th)}$ vs. T_J

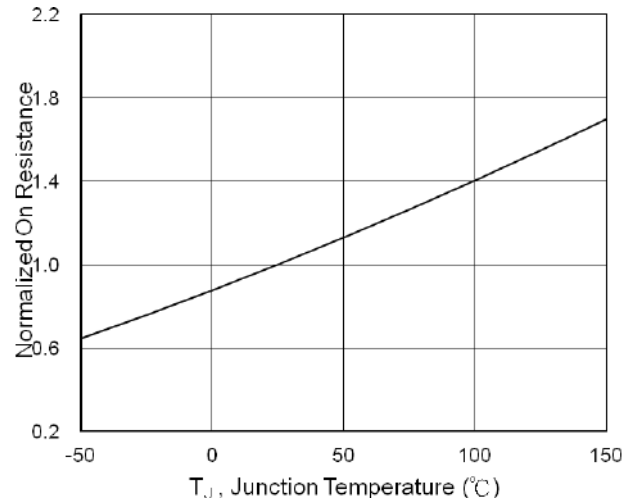


Fig.6 Normalized $R_{DS(ON)}$ vs. T_J

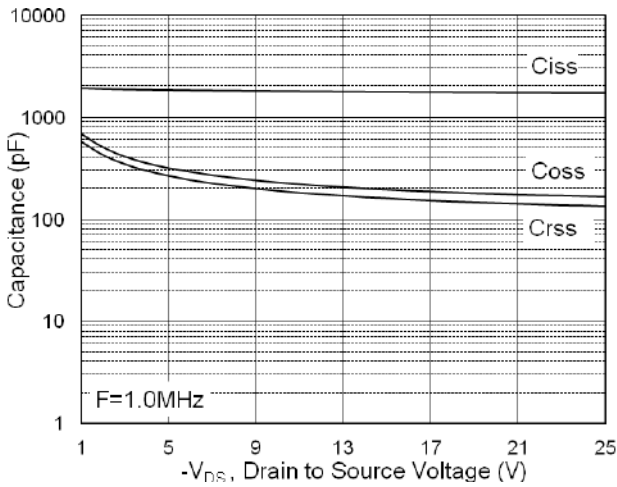


Fig.7 Capacitance

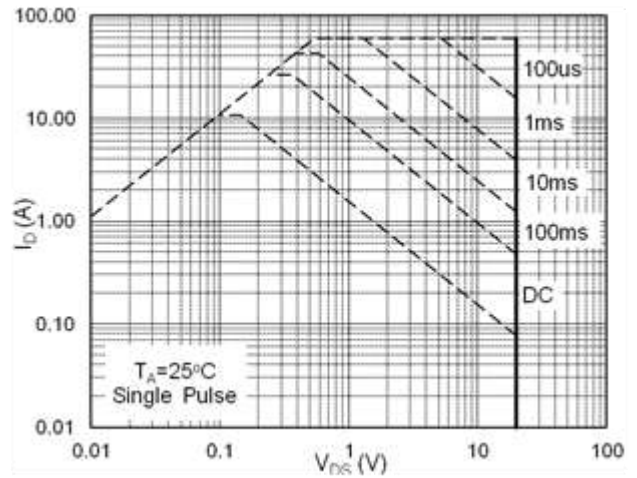


Fig.8 Safe Operating Area

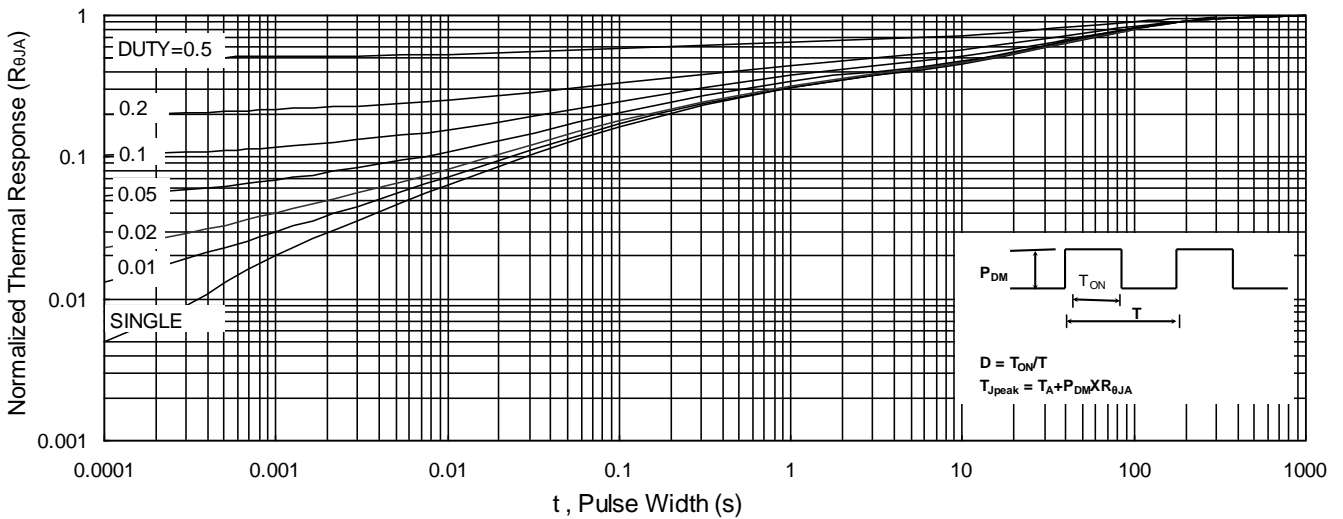


Fig.9 Normalized Maximum Transient Thermal Impedance

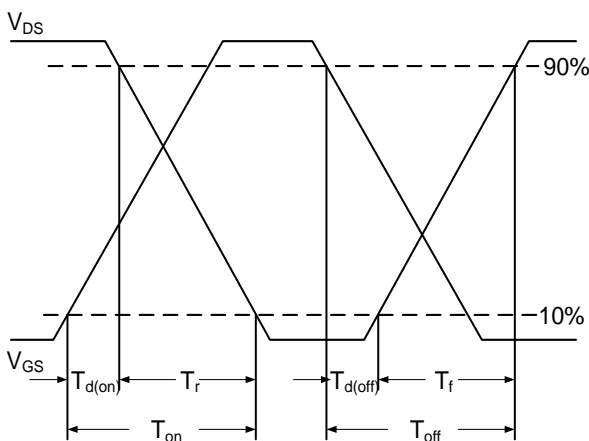


Fig.10 Switching Time Waveform

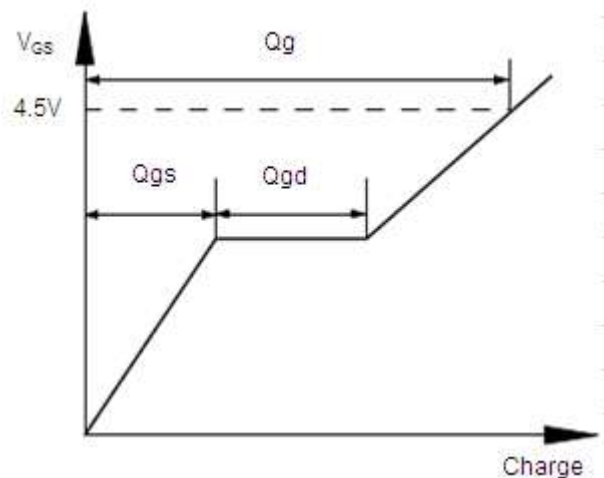


Fig.11 Gate Charge Waveform

➤ Recommend IR Reflow Soldering Thermal Profile

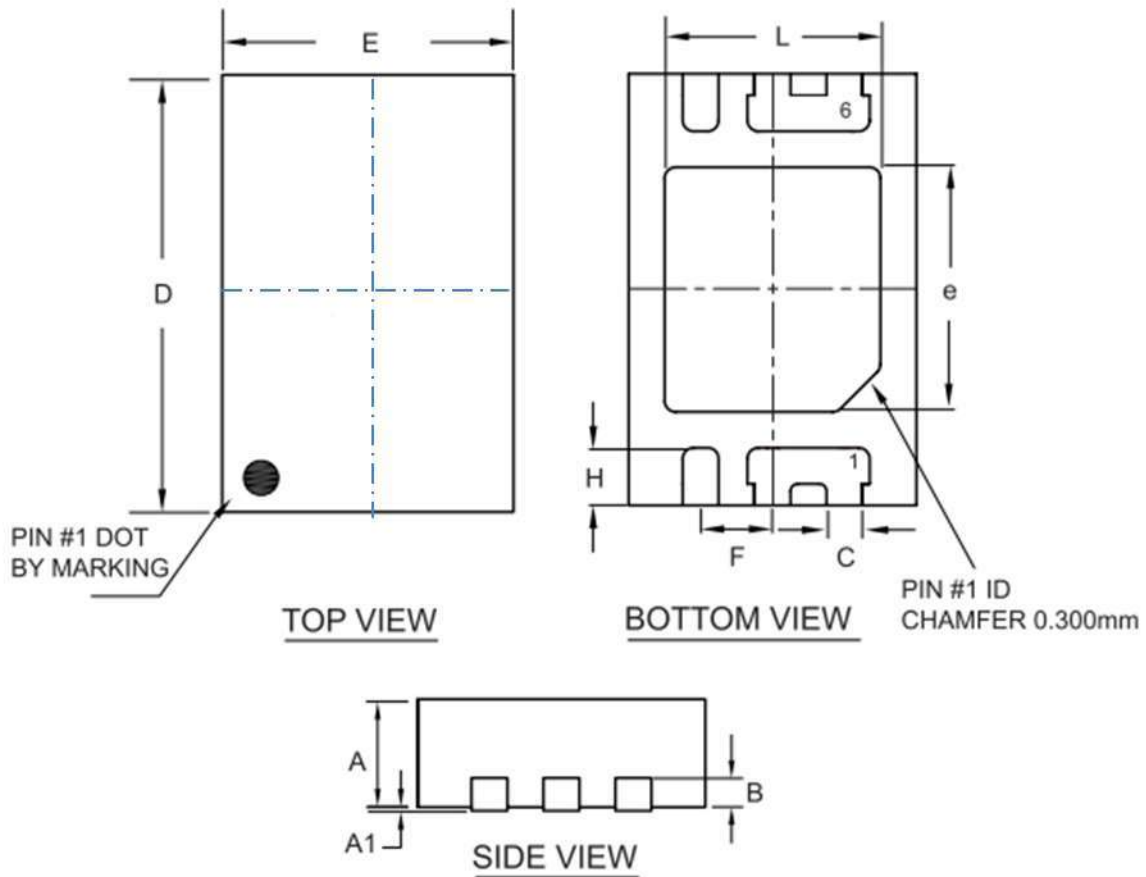


Profile Feature	Pb-Free Assembly Profile
Temperature Min. (T _{smin})	150°C
Temperature Max. (T _{smax})	200°C
Time (t _s) from (T _{smin} to T _{smax})	60-120 seconds
Average Ramp-up Rate (t _L to t _P)	3°C/second max.
Liquidous Temperature (T _L)	217°C
Time (t _L) Maintained Above (T _L)	60 – 150 seconds
Peak Temperature	260°C +0°C / -5°C
Time (t _P) within 5°C of actual Peak Temperature	30 seconds
Ramp-down Rate (T _P to T _L)	6°C/second max
Time 25°C to Peak Temperature	8 minutes max.

➤ Ordering Information

Part Number	Description	Quantity
PAN82TE04F	DFN2X3-6L Reel	3000 pcs

➤ Package Information (DFN2X3-6L)



SYMBOLS	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	0.700	0.800	0.028	0.031
A1	0.000	0.050	0.000	0.002
D	2.950	3.050	0.116	0.120
E	1.950	2.050	0.077	0.081
H	0.350	0.450	0.014	0.018
L	1.450	1.550	0.057	0.061
e	1.650	1.750	0.065	0.069
B	0.195	0.211	0.0076	0.008
C	0.200	0.300	0.008	0.012
F	0.500 BSC		0.020 BSC	

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